

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)	DIVISIONAL
)	PATENT APPLICATION
Inventors: Yanjun Ma,)	
Douglas James Tweet, and)	September 11, 2003
David Russell Evans)	
)	
Serial No.: Unknown)	Attorney Docket No.
)	SLA0828 (SLA0514D)
Filed: Herewith)	
)	Parent Application:
Title: INTEGRATED CIRCUIT)	
METAL OXIDE)	Serial No. 10/072,248
SEMICONDUCTOR)	Filed: February 7, 2002
TRANSISTOR)	
)	Pending in Group Art
)	Unit 2814
)	
)	Examiner: Douglas A.
)	Wille
)	
)	Anticipated Classification:
)	Class: 257
)	Subclass: 288

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10/661429
09/11/03

**CERTIFICATE OF MAILING BY "EXPRESS MAIL"
UNDER 37 C.F.R. 1.10**

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Victoria A. Woods

Victoria Woods
Signature Date: September 11, 2003

DIVISIONAL APPLICATION UNDER 37 C.F.R. §1.53(b)

Mail Stop PATENT APPLICATION
Hon. Commissioner for Patents
P.O. Box 1450
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Sir:

The undersigned, attorney-of-record in parent application Serial No. 10/072,248, filed February 7, 2002, entitled "Silicon-Germanium MOSFET with Deposited Gate Dielectric and Metal Gate Electrode and Method for Making the Same," hereby requests the filing of a Divisional Application under the provisions of 37 C.F.R. §1.53(b).

Identification of the Parent of the Present Divisional Application:

Serial No.:	10/072,248
Filed:	February 7, 2002
Title:	Silicon-Germanium MOSFET with Deposited Gate Dielectric and Metal Gate Electrode and Method for Making the Same
Inventors:	Yanjun Ma, Douglas James Tweet, and David Russell Evans
Status:	Pending

Copy of Present Divisional Application:

Enclosed is a copy of the present divisional application which incorporates the following changes from the as-filed specification and drawings in parent application Serial No. 10/072,248: The titled has been revised, an introductory cross-reference section has been added on page 1, and formal drawings have replaced the as-filed drawings. The present divisional application includes the following papers:

X No. of Pages in Specification: 18 No. of Claims: 19
X No. of Sheets of Drawings: 5 Formal: X or Informal: ____
X Copy of the Declaration (signed by all inventors) in parent application Serial No. 10/072,248.

X Copy of the Power of Attorney in parent application Serial No. 10/072,248.

Parent application Serial No. 10/072,248, filed February 7, 2002, entitled "Silicon-Germanium MOSFET with Deposited Gate Dielectric and Metal Gate Electrode and Method for Making the Same" is hereby incorporated herein by reference.

Delete the Following Inventor(s) for This Application: None

Amendments:

X Please amend the enclosed specification as follows:

Cancel claims 8-19.

Filing Fee

The Divisional Patent Application filing fee is calculated as shown below after cancellation of claims 8 through 19:

No. Filed	No. Extra	Rate Small Entity/ Other Than Small Entity	
Basic Fee		\$375.00 \$750.00	\$ 750.00
Total Claims <u>7</u> (20)	= <u>0</u> X	\$ 9.00 \$18.00 =	\$ 36.00
Independent Claims <u>1</u> (3)	= <u>0</u> X	\$42.00 \$84.00 =	\$ 00.00
First Presentation of Multiple Dependent Claim(s) <u>0</u>		\$140.00 \$280.00 =	\$ 00.00
Total PATENT APPLICATION FILING FEE			\$ 750.00

* If the difference is less than zero, enter "O".

** Count claims after any amendment.

The total fee associated with this communication is as follows:

Patent application filing fee	\$ 750.00
	=====
TOTAL FEE DUE:	\$ 750.00

Method of Payment of Fees

- ☐ A check in the amount of the TOTAL FEE DUE is enclosed.
- ☒ Please charge Deposit Account No. 19-1457 in the amount of \$ 786.00.
A duplicate copy of this authorization is enclosed.
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Correspondence Address

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Date: 9/11/03

Respectfully submitted,

By: 

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